

FEATURES

- **Generates Three Voltages:**
 5.1V at 10mA
 –5V, –10V, or –15V at 500 μ A
 10V or 15V at 500 μ A
- **Better than 90% Efficiency**
- **Low Output Ripple: Less than 5mV_{P-P}**
- **Complete 1mm Component Profile Solution**
- **Controlled Power-Up Sequence: $AV_{DD}/V_{GL}/V_{GH}$**
- **All Outputs Disconnected and Actively Discharged in Shutdown**
- **Low Noise Fixed Frequency Operation**
- **Frequency Reduction Input for High Efficiency in Blank Mode**
- **Ultralow Quiescent Current: 75 μ A (Typ) in Scan Mode**
- **Available in a 3mm $\times$ 3mm 16-Pin QFN Package**

APPLICATIONS

- Cellular Handsets with Color Display
- Handheld Instruments
- PDA

DESCRIPTION

The LTC[®]3450 is a complete power converter solution for small thin film transistor (TFT) liquid crystal display (LCD) panels. The device operates from a single Lithium-Ion cell, 2- to 3-cell alkaline input or any voltage source between 1.5V and 4.6V.

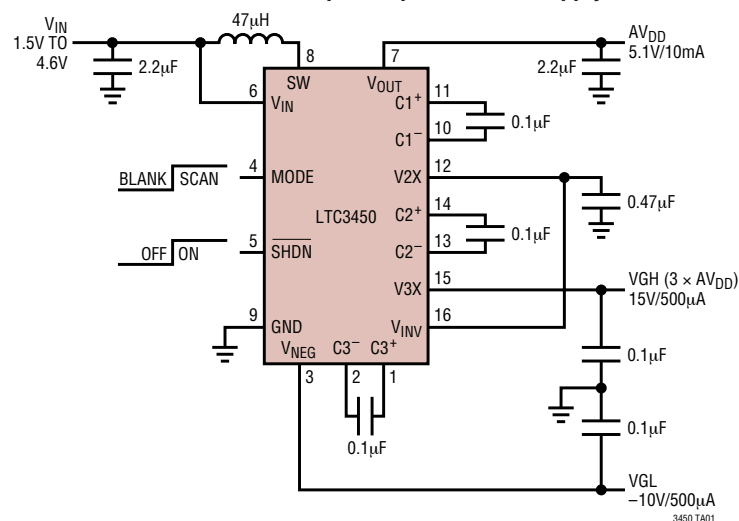
The synchronous boost converter generates a low noise, high efficiency 5.1V, 10mA supply. Internal charge pumps are used to generate 10V, 15V, and –5V, –10V or –15V. Output sequencing is controlled internally to insure proper initialization of the LCD panel.

A master shutdown input reduces quiescent current to <2 μ A and quickly discharges each output for rapid turn off of the LCD panel. The LTC3450 is offered in a low profile (0.75mm), 3mm $\times$ 3mm 16-pin QFN package, minimizing the solution profile and footprint.

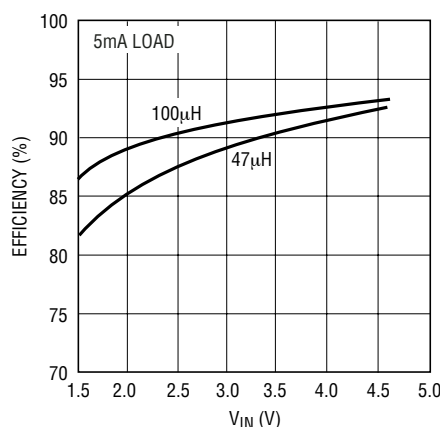
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TYPICAL APPLICATION

5.1V, –10V, 15V Triple Output TFT-LCD Supply



AV_{DD} Efficiency vs V_{IN}



3450 TA01b

ABSOLUTE MAXIMUM RATINGS

(Note 1) (Referred to GND)

V_{IN} , SW	–0.3 to 7V
SHDN, MODE	–0.3 to 7V
V_{OUT}	–0.3 to 5.5V
V_{NEG}	–17V to 0.3V
Operating Temperature Range	
LTC3450E (Note 4)	–40°C to 85°C
Storage Temperature Range	
	–65°C to 125°C

PACKAGE/ORDER INFORMATION

UD PACKAGE 16-LEAD (3mm × 3mm) PLASTIC QFN EXPOSED PAD IS V_{NEG} (PIN 17) MUST BE SOLDERED TO PCB $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 68^{\circ}\text{C/W}$	ORDER PART NUMBER
	LTC3450EUD
	UD PART MARKING
	LAAC

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. $V_{IN} = 3.6\text{V}$, $V_{OUT} = 5.2\text{V}$ unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input Voltage Range	●	1.5		4.6	V
V_{IN} Quiescent Supply Current	MODE = V_{IN}		75	130	μA
V_{OUT} Quiescent Supply Current	MODE = V_{IN}		80		μA
V_{IN} Quiescent Supply Current	MODE = GND		30	50	μA
V_{OUT} Quiescent Supply Current	MODE = GND		13		μA
V_{IN} Quiescent Current	SHDN = GND, V_{OUT} OPEN		0.01	2	μA
5V Boost Regulator					
V_{OUT} Output Voltage	Load on $V_{OUT} = 5\text{mA}$	5.049	5.100	5.151	V
V_{OUT} Efficiency	Load on $V_{OUT} = 5\text{mA}$, (Note 2)		90		%
V_{OUT} Maximum Output Current	$L = 47\mu\text{H}$, (Note 2)		11		mA
Switch Current Limit		90	120		mA
Switching Frequency—Boost	MODE = V_{IN}		550		kHz
Switching Frequency—Boost	MODE = GND		15.62		kHz
Charge Pumps					
V2X Output Voltage	Load on V2X = 100 μA	● 9.792	10.1	10.608	V

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{IN} = 3.6\text{V}$, $V_{OUT} = 5.2\text{V}$ unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V3X Output Voltage	Load on V3X = $100\mu\text{A}$	●	14.688	15.2	15.912	V
V2X Efficiency	Load on V2X = $100\mu\text{A}$, (Note 2)			90		%
V3X Efficiency	Load on V3X = $100\mu\text{A}$, (Note 2)			80		%
Output Impedance V2X, V3X	Flying Capacitors = $0.1\mu\text{F}$			1		$\text{k}\Omega$
V_{NEG} Output Voltage	Load on $V_{NEG} = 100\mu\text{A}$, $V_{INV} = V2X$	●	-10.608	-10.1	-9.792	V
V_{NEG} Efficiency	Load on $V_{NEG} = 100\mu\text{A}$ (Note 2)			80		%
Output Impedance V_{NEG}	Flying Capacitor = $0.1\mu\text{F}$			1		$\text{k}\Omega$
Switching Frequency Charge Pumps	MODE = V_{IN}			62.5		kHz
Switching Frequency Charge Pumps	MODE = GND			3.75		kHz
V_{NEG} to V3X Delay	(Note 3)		3	4	10	ms
Logic Inputs						
SHDN Pin Threshold		●	0.4	0.77	1.2	V
MODE Pin Threshold				1.6		V

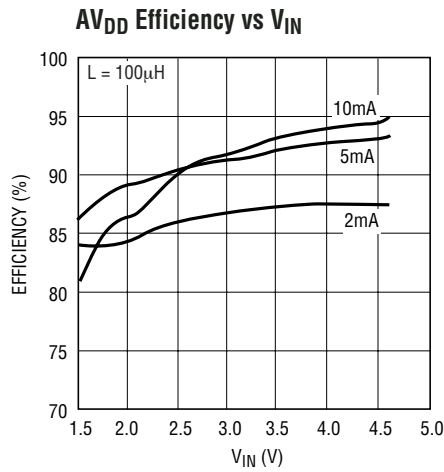
Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Specification is guaranteed by design and not 100% tested in production.

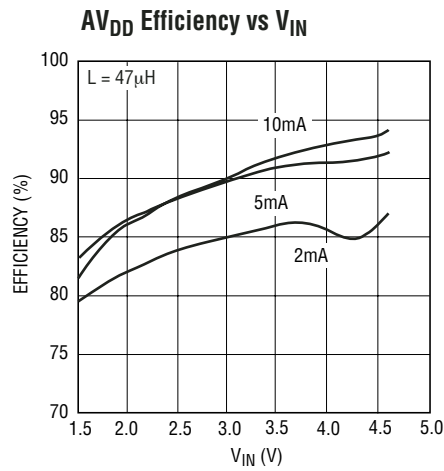
Note 3: Measured from point at which V_{NEG} crosses -5V to point at which $C2^-$ starts switching.

Note 4: The LTC3450E is guaranteed to meet performance specifications from 0°C to 70°C . Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

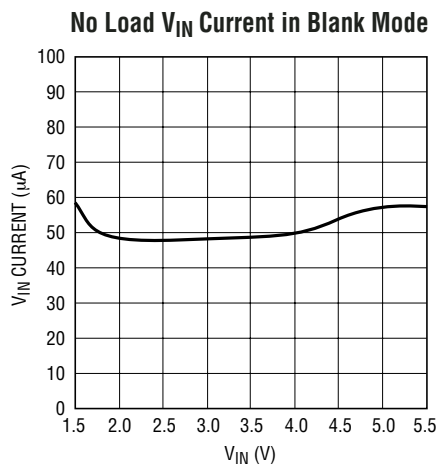
TYPICAL PERFORMANCE CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)



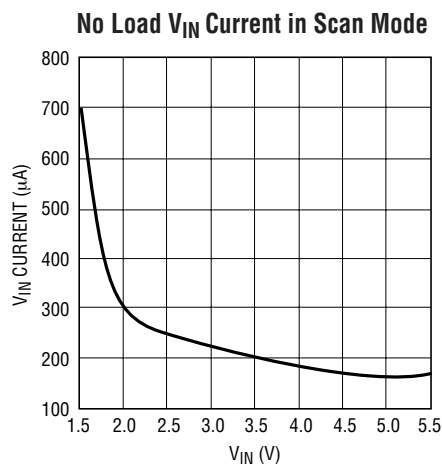
3450 G02



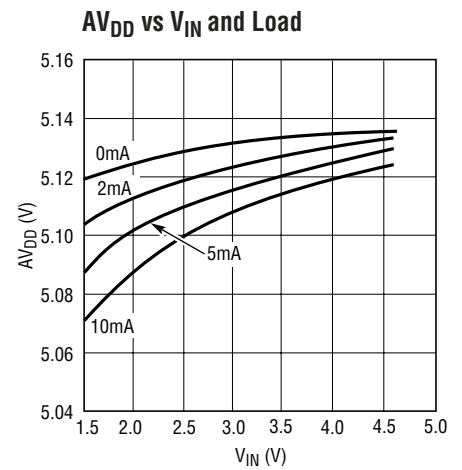
3450 G03



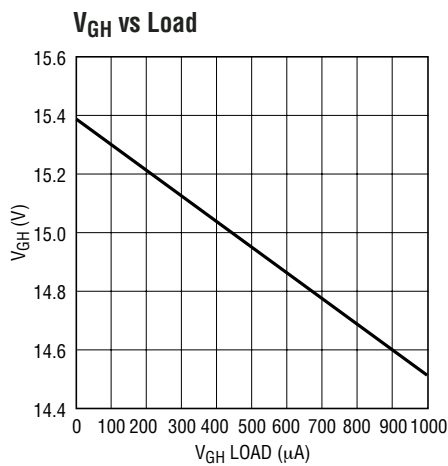
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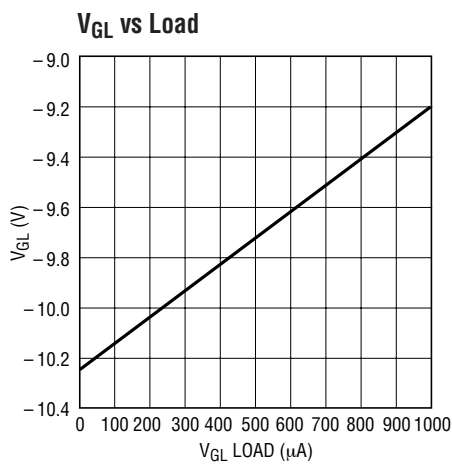
3450 G05



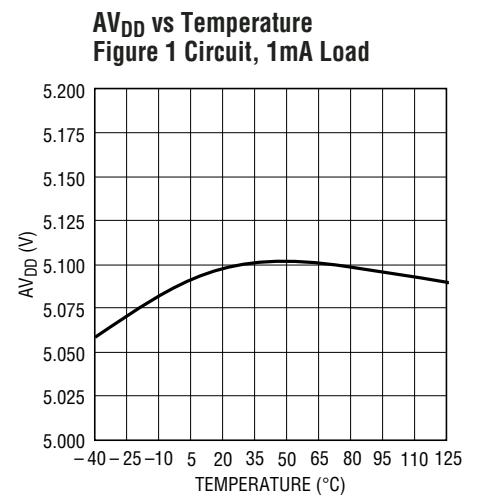
3450 G06



3450 G07



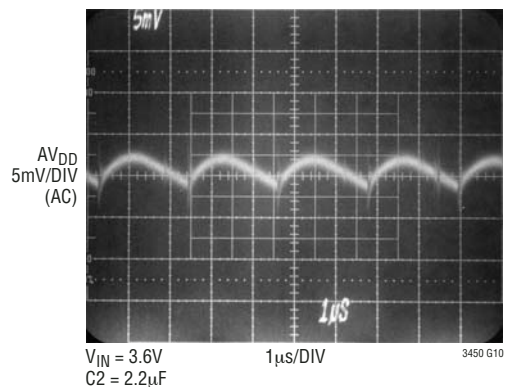
3450 G08



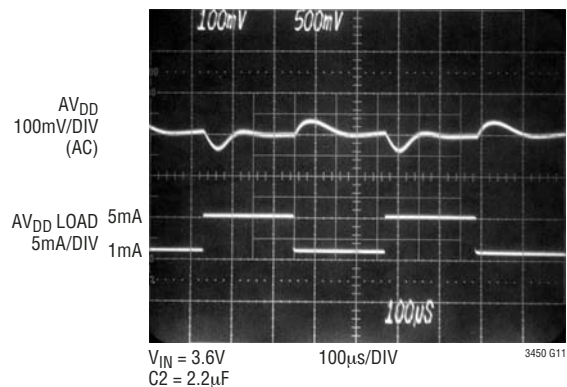
3450 G09

TYPICAL PERFORMANCE CHARACTERISTICS

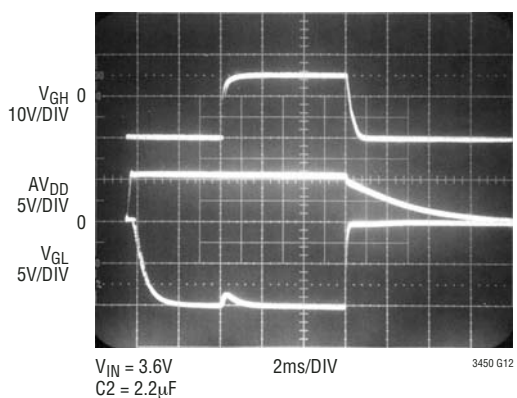
AV_{DD} Ripple Voltage
 AV_{DD} Load = 5mA



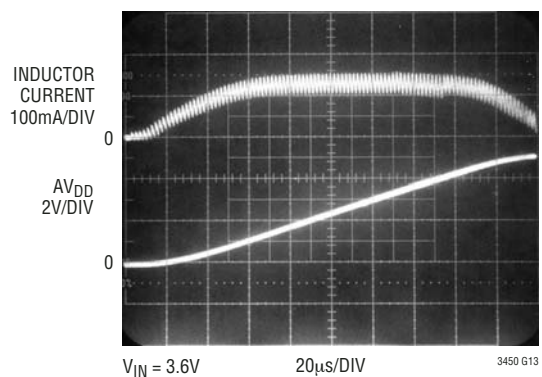
AV_{DD} Transient Response



AV_{DD} , V_{GL} , V_{GH} Turn-On and Turn-Off Sequence



AV_{DD} Turn-On Showing Inrush Current Limiting



PIN FUNCTIONS

C3⁺ (Pin 1): Charge Pump Inverter Flying Capacitor Positive Node. The charge pump inverter flying capacitor is connected between C3⁺ and C3⁻. The voltage on C3⁺ will alternate between GND and V_{INV} at an approximate 50% duty cycle while the inverting charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

C3⁻ (Pin 2): Charge Pump Inverter Flying Capacitor Negative Node. The charge pump inverter flying capacitor is connected between C3⁺ and C3⁻. The voltage on C3⁻ will alternate between GND and V_{NEG} at an approximate 50% duty cycle while the inverting charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

V_{NEG} (Pin 3): Charge Pump Inverter Output. V_{NEG} can be either -5V or -10V depending on where V_{INV} is connected. V_{NEG} should be bypassed to GND with at 0.1μF or larger X5R type ceramic capacitor. V_{NEG} can also be configured for -15V with two external low current Schottky diodes (see Applications section).

MODE (Pin 4): Drive MODE high to force the LTC3450 into high power (scan) mode. Drive MODE low to force the LTC3450 into low power (blank) mode. The output voltages remain active with the MODE pin driven low but with reduced output current capability. MODE must be pulled up to V_{IN} or higher on initial application of power in order for proper initialization to occur.

SHDN (Pin 5): Master Shutdown Input for the LTC3450. Driving SHDN low disables all IC functions and reduces quiescent current from the battery to less than 2μA. Each generated output voltage is actively discharged to GND in shutdown through internal pull down devices. An optional RC network on SHDN provides a slower ramp up of the boost converter inductor current during startup (soft-start).

V_{IN} (Pin 6): Input Supply to the LTC3450. Connect V_{IN} to a voltage source between 1.5V and 4.6V. Bypass V_{IN} to GND with a 2.2μF X5R ceramic capacitor.

V_{OUT} (Pin 7): Main 5.1V Output of the Boost Regulator and Input to the Voltage Doubler Stage. Bypass V_{OUT} with a low ESR, ESL ceramic capacitor (X5R type) between 2.2μF and 10μF.

SW (Pin 8): Switch Pin. Connect the inductor between SW and V_{IN}. Keep PCB trace lengths as short and wide as possible to reduce EMI and voltage overshoot. If the inductor current falls to zero, the internal P-channel MOSFET synchronous rectifier is turned off to prevent reverse charging of the inductor and an internal switch connects SW to V_{IN} to reduce EMI.

GND (Pin 9): Signal and Power Ground for the LTC3450. Provide a short direct PCB path between GND and the output filter capacitor(s) on V_{OUT}, V2X, V3X and V_{NEG}.

C1⁻ (Pin 10): Charge Pump Doubler Flying Capacitor Negative Node. The charge pump doubler flying capacitor is connected between C1⁺ and C1⁻. The voltage on C1⁻ will alternate between GND and V_{OUT} at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

C1⁺ (Pin 11): Charge Pump Doubler Flying Capacitor Positive Node. The charge pump doubler flying capacitor is connected between C1⁺ and C1⁻. The voltage on C1⁺ will alternate between V_{OUT} and V2X at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

V2X (Pin 12): Charge Pump Doubler Output. This output is 10.2V (nom) at no load and is capable of delivering up to 500μA to a load. V2X should be bypassed to GND with a 0.47μF X5R type ceramic capacitor.

C2⁻ (Pin 13): Charge Pump Tripler Flying Capacitor Negative Node. The charge pump tripler flying capacitor is connected between C2⁺ and C2⁻. The voltage on C2⁻ will alternate between GND and V_{OUT} at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

C2⁺ (Pin 14): Charge Pump Tripler Flying Capacitor Positive Node. The charge pump tripler flying capacitor is connected between C2⁺ and C2⁻. The voltage on C2⁺ will alternate between V2X and V3X at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

PIN FUNCTIONS

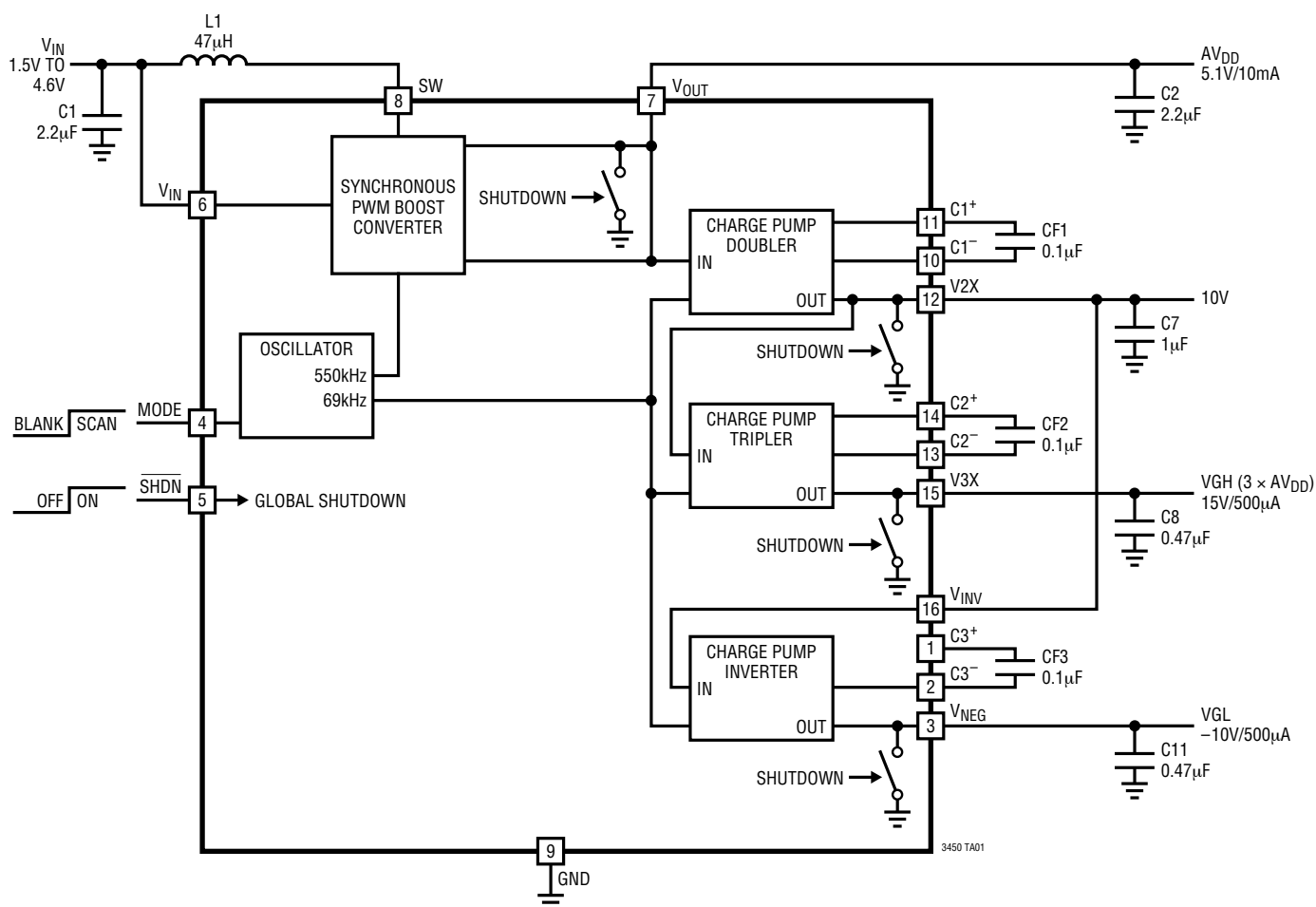
V3X (Pin 15): Charge Pump Tripler Output. This output is 15.3V (nom) at no load and is capable of delivering up to 500 μ A to a load. V3X should be bypassed to GND with a 0.1 μ F X5R type ceramic capacitor.

V_{INV} (Pin 16): Positive Voltage Input for the Charge Pump Inverter. The charge pump inverter will generate a negative voltage corresponding to the voltage applied to V_{INV}.

Connecting V_{INV} to 5V or 10V will generate –5V or –10V respectively on V_{NEG}. See Applications section for –15V generation.

Exposed Pad (Pin 17): The exposed pad must be connected to V_{NEG} (Pin 3) on the PCB. **Do not connect the exposed pad to GND.**

BLOCK DIAGRAM



OPERATION

The LTC3450 is a highly integrated power converter intended for small TFT-LCD display modules. A fixed frequency, synchronous PWM boost regulator generates a low noise 5.1V, 10mA bias at greater than 90% efficiency from an input voltage of 1.5V to 4.6V. Three charge pump converters use the 5.1V output to generate 10V, 15V and $-5V$, $-10V$ or $-15V$ at load currents up to $500\mu A$. Each converter is frequency synchronized to the main 550kHz (nominal) boost converter. The generated output voltages are internally sequenced to insure proper initialization of the LCD panel. A digital shutdown input rapidly discharges each generated output voltage to provide a near instantaneous turn-off of the LCD display.

Boost Converter

The synchronous boost converter utilizes current mode control and includes internally set control loop and slope compensation for optimized performance and simple design. Only three external components are required to complete the design of the 5.1V, 10mA boost converter. The high operation frequency produces very low output ripple and allows the use of small low profile inductors and tiny external ceramic capacitors. The boost converter also disconnects its output from V_{IN} during shutdown to avoid loading the input power source. Softstart produces a controlled ramp of the converter input current during startup, reducing the burden on the input power source. Very low operating quiescent current and synchronous operation allow for greater than 90% conversion efficiency.

The MODE input reduces the boost converter operating frequency by approximately 8x when driven high and reduces the output power capability of the boost converter. MODE is asserted when the polysilicon TFT-LCD display is in its extremely low power blank condition. The

boost converter further reduces its quiescent current in this mode, delivering both lower input (battery) current drain and low noise operation.

Charge Pumps

The LTC3450 includes three separate charge pump converters which generate 10V, 15V and either $-5V$, $-10V$ or $-15V$. Each output can deliver a maximum of $500\mu A$. The charge pumps feature fixed frequency, open-loop operation for high efficiency and lowest noise performance. The charge pump converters operate at 1/8 the boost converter frequency and include internal charge transfer switches. Thus, each charge pump requires only two small external capacitors, one to transfer charge, and one for filtering. Similar to the boost converter, the charge pumps operating frequency reduces to approximately 4kHz in blank mode, maintaining low noise operation but at reduced output current capability.

Output Sequencing

Refer to the following text and Figure 1 for the LTC3450 power-up sequence. When input power is applied, the boost converter initializes and charges its output towards the final value of 5.1V. When the boost converter output reaches approximately 90% of its final value (4.5V), an internal 5V OK signal is asserted which allows the charge pump doubler to begin operation toward its final goal of 10V. Approximately 1ms later, the charge pump inverter begins operation toward its final goal of either $-5V$ or $-10V$ depending on the connection of the V_{INV} input. When the $-5V$ or $-10V$ output (V_{NEG}) reaches approximately 50% of its final value, a 4ms (nominal) timeout period begins. At the conclusion of the 4ms timeout period, the charge pump tripler is allowed to begin operation, which will eventually charge V_{3X} to 15V (nominal).

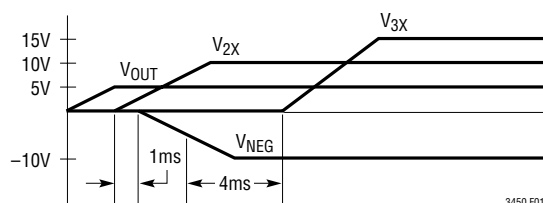


Figure 1. Output Sequencing

APPLICATIONS INFORMATION

Inductor Selection

Inductors in the range of 47 μ H to 100 μ H with saturation current (I_{SAT}) ratings of at least 150mA are recommended for use with the LTC3450. Ferrite core materials are strongly recommended for their superior high frequency performance characteristics. A bobbin or toroid type core will reduce radiated noise. Inductors meeting these requirements are listed in Table 1.

Table 1. Recommended Inductors

PART NUMBER	L (μ H)	MAX DCR (Ω)	HEIGHT (mm)	VENDOR
CLQ4D10-470	47	1.28	1.2	Sumida (847) 956-0666 www.sumida.com
CLQ4D10-101	100	3.15		
CMD4D08-470	47	1.6	1.0	
DO1606-473	47	1.1	2.0	Coilcraft (847) 639-6400 www.coilcraft.com
DO1606-104	100	2.3		
DT1608-473	47	0.34	2.92	
DT1608-104	100	1.1		
LQH43MN470J03	47	1.5	2.6	Murata www.murata.com
LQH43MN101J03	100	2.5		
DU6629-470M	47	0.64	2.92	Coev Magnetics www.circuitprotection.com
DU6629-101M	100	1.27		

Capacitor Selection

The boost converter requires two capacitors. The input capacitor should be an X5R type of at least 1 μ F. The V_{OUT} capacitor should also be an X5R type between 2.2 μ F and 10 μ F. A larger capacitor (10 μ F) should be used if lower output ripple is desired or the output load required is close to the 10mA maximum.

The charge pumps require flying capacitors of at least 0.1 μ F to obtain specified performance. Ceramic X5R types are strongly recommended for their low ESR and ESL and capacitance versus bias voltage stability. The filter capacitor on V2X should be at least 0.1 μ F. A 0.47 μ F or larger capacitor on V2X is recommended if V_{INV} is connected to V2X. The filter capacitors on V3X and V_{NEG} should be 0.1 μ F or larger. Please be certain that the capacitors used are rated for the maximum voltage with adequate safety margin. Refer to Table 2 for a listing of capacitor vendors.

Table 2. Capacitor Vendor Information

Supplier	Phone	Website
AVX	(803) 448-9411	www.avxcorp.com
Murata	(714) 852-2001	www.murata.com
Taiyo Yuden	(408) 573-4150	www.t-yuden.com

Soft-Start

Soft-start operation provides a gradual increase in the current drawn from the input power source (usually a battery) during initial startup of the LTC3450, eliminating the inrush current which is typical in most boost converters. This reduces stress on the input power source, boost inductor and output capacitor, reduces voltage sag on the battery and increases battery life. The rate at which the input current will increase is set by two external components (R_{SS} and C_{SS}) connected to SHDN (refer to Figure 2). Upon initial application of power or release of a pull down switch on SHDN, the voltage on SHDN will increase relative to the $R \cdot C$ time constant or $R_{SS} \cdot C_{SS}$. After one time constant SHDN will rise to approximately 63.2% of the voltage on V_{IN} . From 0V to approximately 0.77V on SHDN, no switching will occur because the shutdown threshold is 0.77V (typ). From 0.77V to 1V the maximum switch pin current capability of the LTC3450 will gradually increase from near zero to the maximum current limit. An R_{SS} in the range of 1M Ω to 10M Ω is recommended. If SHDN is driven high with a logic signal, the input current will gradually increase to its maximum value in approximately 50 μ s.

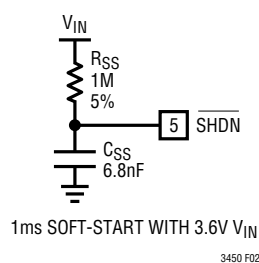


Figure 2. Soft-Start Component Configuration

Printed Circuit Board Layout Guidelines

High speed operation of the LTC3450 demands careful attention to PCB layout. You will not get advertised performance with careless layout. Figure 3 shows the recommended component placement for a single layer PCB. A multilayer board with a separate ground plane is ideal but not absolutely necessary.



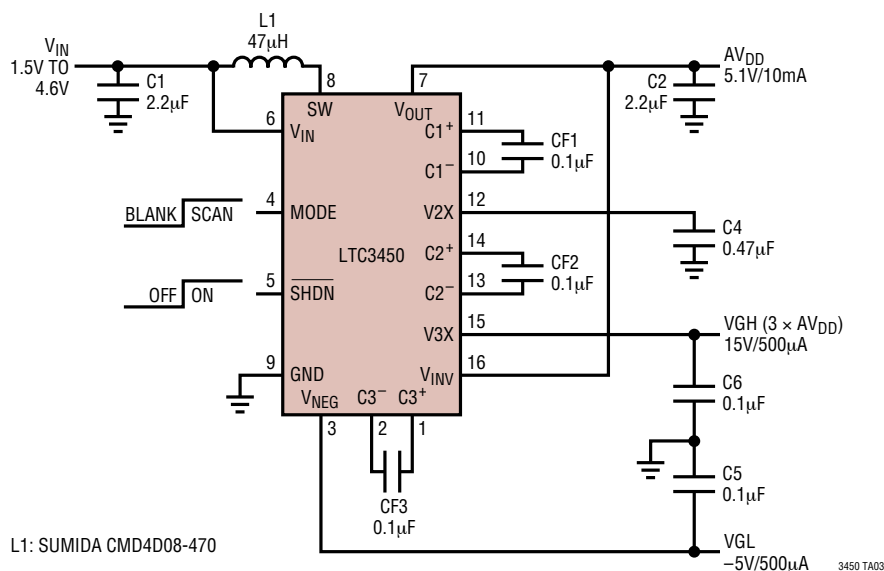
Figure 3. Suggested Layout

TYPICAL APPLICATION

D1, D2: DUAL SCHOTTKY DIODE, PANASONIC MA704WKCT
L1: SUMIDA CMD4D08-470

TYPICAL APPLICATION

5.1V, -5V, 15V Triple Output TFT-LCD Supply



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1310	1.5A I_{SW} , 4.5MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 2.75V to 18V, V_{OUT} = 35V, I_Q = 12mA, I_{SD} = <1µA MSE Package
LT1613	550mA I_{SW} , 1.4MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 0.9V to 10V, V_{OUT} = 34V, I_Q = 3mA, I_{SD} = <1µA ThinSOT Package
LT1615/LT1615-1	300mA/80mA I_{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = 34V, I_Q = 20µA, I_{SD} = <1µA ThinSOT Package
LT1940	Dual Output 1.4A I_{OUT} , Constant 1.1MHz, High Efficiency Step-Down DC/DC Converter	V_{IN} : 3V to 25V, V_{OUT} (MIN) = 1.2V, I_Q = 2.5mA, I_{SD} = <1µA TSSOP-16E Package
LT1944	Dual Output 350mA I_{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = 34V, I_Q = 20µA, I_{SD} = <1µA MS Package
LT1944-1	Dual Output 150mA I_{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = 34V, I_Q = 20µA, I_{SD} = <1µA MS Package
LT1945	Dual Output, Pos/Neg, 350mA I_{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = ±34V, I_Q = 20µA, I_{SD} = <1µA MS Package
LT1946/LT1946A	1.5A I_{SW} , 1.2MHz/2.7MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 2.45V to 16V, V_{OUT} = 34V, I_Q = 3.2mA, I_{SD} = <1µA MS8 Package
LT1947	Triple Output (for TFT-LCD) 1.1A I_{SW} , 3MHz High Efficiency Step-Up DC/DC Converter	V_{IN} : 2.7V to 8V, V_{OUT} = 34V, I_Q = 9.5mA, I_{SD} = <1µA MS Package
LT1949/LT1949-1	550mA I_{SW} , 600kHz/1.1MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.5V to 12V, V_{OUT} = 28V, I_Q = 4.5mA, I_{SD} = <25µA S8, MS8 Packages
LTC3400/LTC3400B	600mA I_{SW} , 1.2MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.85V to 5V, V_{OUT} = 5V, I_Q = 19µA/300µA, I_{SD} = <1µA ThinSOT Package
LTC3401	1A I_{SW} , 3MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, V_{OUT} = 5V, I_Q = 38µA, I_{SD} = <1µA, MS Package
LTC3402	2A I_{SW} , 3MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, V_{OUT} = 5V, I_Q = 38µA, I_{SD} = <1µA, MS Package

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